TOSHIBA THYRISTOR SILICON PLANAR TYPE

SF25GZ51, SF25JZ51

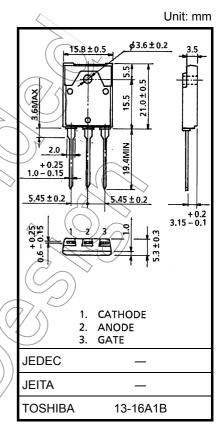
MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage: VDRM = 400V, 600 V
 Repetitive Peak Reverse Voltage: VRRM = 400V, 600 V
- Average On-State Current: IT (AV) = 25 A
- Isolation Voltage: V_{Isol} = 1500 V AC

MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	(UNIT)	
Repetitive Peak Off-State Voltage and	SF25GZ51	V_{DRM}	400		
Repetitive Peak Reverse Voltage	SF25JZ51	VRRM	600		
Non-Repetitive Peak Reverse Voltage	SF25GZ51	V_{RSM}	500	V	
(Non-Repetitive < 5 ms, $T_j = 0\sim125$ °C)	SF25JZ51	VRSM <	720		
Average On-State Current (Half Sine Waveform)		I _T (AV)	25	A	
R.M.S On-State Current		I _{T (RMS)}	39	Α \	
Peak One Cycle Surge On-State Current (Non-Repetitive)		(12M)	350 (50 Hz)	A	
			385 (60 Hz)		
I ² t Limit Value		∑∕ ⟨\¹²t	612 A ² s		
Critical Rate of Rise of On Current	di / dt	(100/	A / μs		
Peak Gate Power Dissipation		P _{GM}	5	W	
Average Gate Power Dissipation		P _G (AV)	0.5	W	
Peak Forward Gate Voltage		V _{FGM}	10	V	
Peak Reverse Gate Voltage		V _{RGM}	<u>_</u> 5	V	
Peak Forward Gate Current		(16M	2	Α	
Junction Temperature		Ţ	-40~125	°C	
Storage Temperature Range		Tstg	-40~125	°C	
Isolation Voltage (AC, t = 1	V _{Isol}	1500	V		

Note: di / dt Test Condition i_G = 30mA, t_{qw} = 10µs, $t_{qr} \le 250$ ns

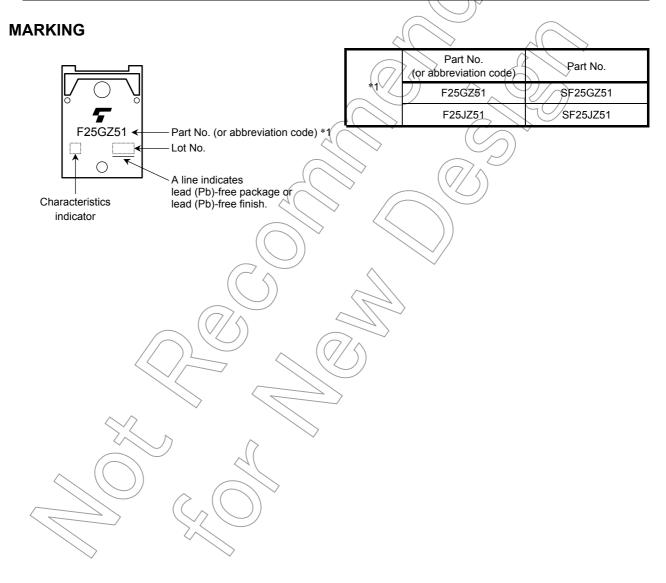


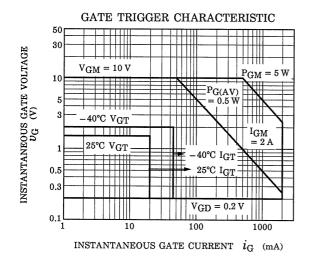
Weight: 5.9 g (typ.)

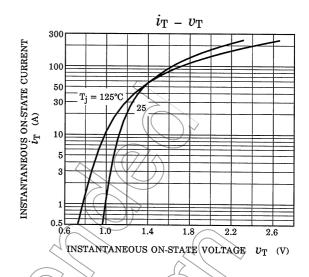


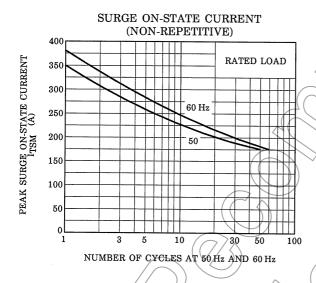
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

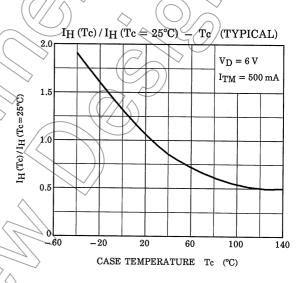
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	20	μΑ
Peak On-State Voltage	V _{TM}	I _{TM} = 80 A	_	_	1.5	V
Gate Trigger Voltage	V _{GT}	V 6 V D: - 10 O	\nearrow	_	1.5	V
Gate Trigger Current	I _{GT}	$V_D = 6 \text{ V}, R_L = 10 \Omega$	(\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	20	mA
Holding Current	lΗ	V _D = 6 V, I _{TM} = 500 mA		7 –	100	mA
Critical Rate of Rise of Off-State Voltage	dv / dt	V _{DRM} = Rated, Tc = 125°C Exponential Rise	\mathcal{D}	50	_	V / µs
Thermal Resistance	R _{th (j-c)}	Junction to Case		_	1.3	°C / W

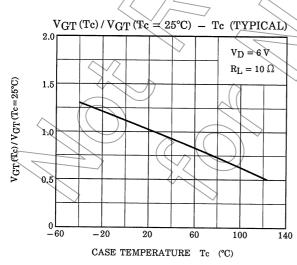


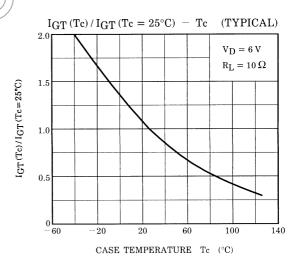


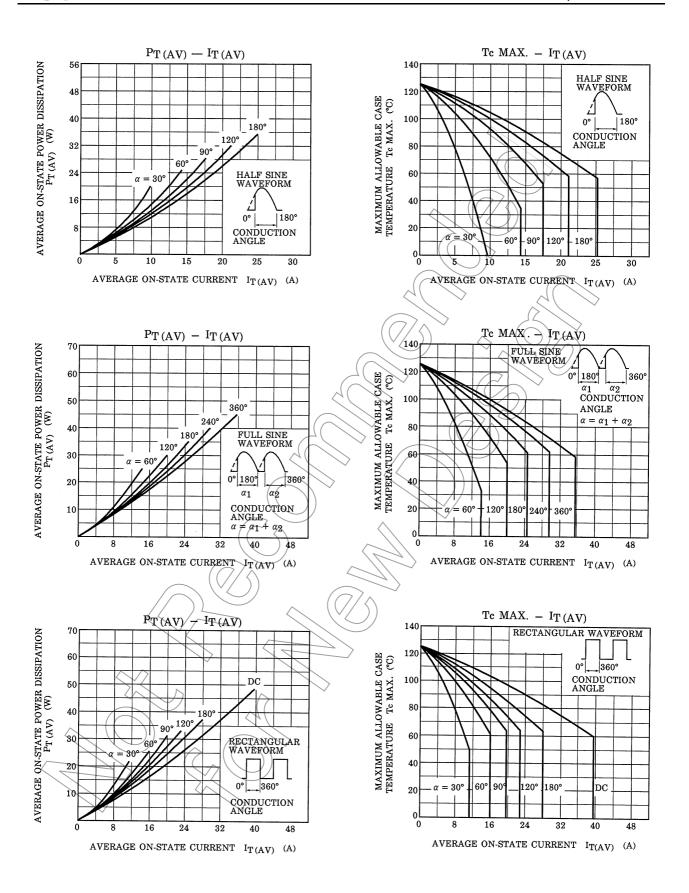


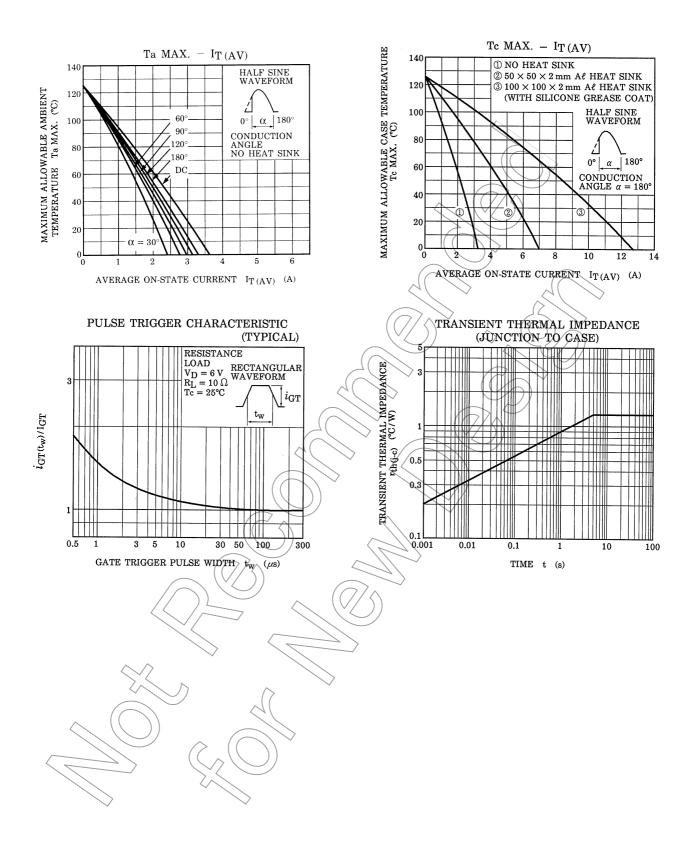














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